

# ECL 4096-BIT BIPOLAR RANDOM ACCESS MEMORY

**MBM 10470A-10**  
**MBM 10470A-15**  
**MBM 10470A-20**

July 1984  
Edition 2.0

## 4096-BIT BIPOLAR ECL RANDOM ACCESS MEMORY

The Fujitsu MBM 10470A is fully decoded 4096-bit ECL read/write random access memory designed for high-speed scratch pad, control and buffer storage applications. This device is organized as 4096 words by one bit, and it features on-chip voltage compensation for improved noise margin.

The MBM 10470A offers extremely small cell and chip size, realized through the use of Fujitsu's patented DOPOS (Doped Polysilicon), as well as IOP-II (Isolation by Oxide and Polysilicon) processing. As a result, very fast access time with high yields and outstanding device reliability are achieved in volume production.

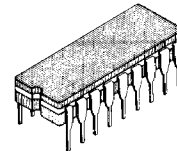
Operation for the MBM 10470A is specified over a temperature range of from 0° to 75°C ( $T_A$  for DIP,  $T_C$  for Flat Package and LCC). It also features 18-pin Ceramic DIP, Flat Package, or LCC. It is fully compatible with industry-standard 10K-series ECL families.

- 4096 words x 1 bit organization
- On-chip voltage compensation for improved noise margin
- Fully compatible with industry-standard 10K-series ECL families
- Address access time: 10 nsec. max. (MBM 10470A-10)  
15 nsec. max. (MBM 10470A-15)  
20 nsec. max. (MBM 10470A-20)
- Chip select access time: 6 nsec. max. (MBM 10470A-10)  
8 nsec. max. (MBM 10470A-15)  
15 nsec. max. (MBM 10470A-20)
- Open emitter output for ease of memory expansion
- Low power dissipation: 0.22mW/bit
- DOPOS and IOP-II processing
- Pin compatible with the F10470

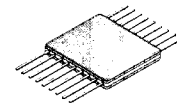
### ABSOLUTE MAXIMUM RATINGS (See NOTE)

Parameter	Symbol	Value	Unit
$V_{EE}$ Pin Potential to Ground Pin	$V_{EE}$	+0.5 to -7.0	V
Input Voltage	$V_{IN}$	+0.5 to $V_{EE}$	V
Output Current (DC, Output High)	$I_{OUT}$	-30	mA
Temperature Under Bias	$T_A$ for DIP	-55 to +125	°C
	$T_C$ for Flat Package and LCC	-55 to +125	
Storage Temperature	$T_{STG}$	-65 to +150	°C

**NOTE:** Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet.



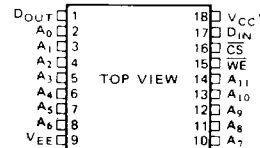
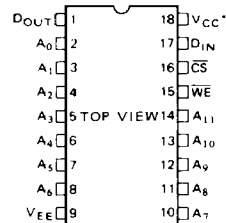
**CERAMIC PACKAGE  
DIP-18C-C01**



**CERAMIC PACKAGE  
FPT-18C-C01**

LCC-18C-F01 : See Page 10

### PIN ASSIGNMENT



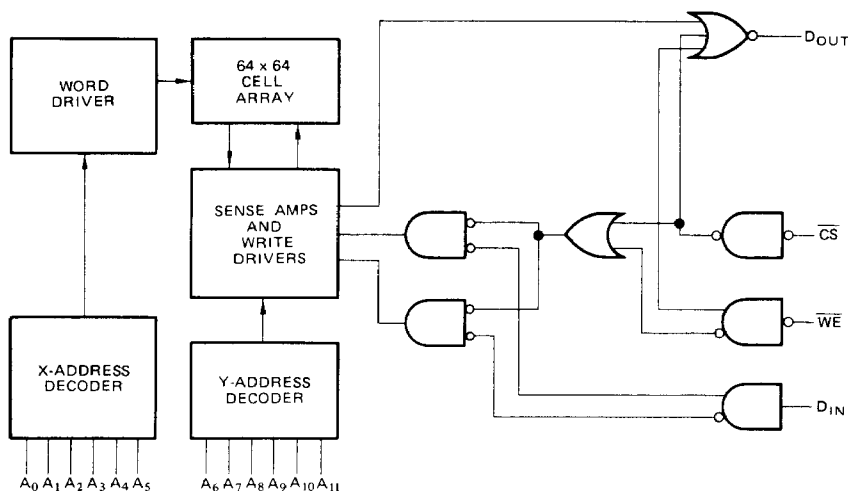
\* $V_{CC}$  grounded

LCC PAD CONFIGURATION : See Page 10

Small geometry bipolar integrated circuits are occasionally susceptible to damage from static voltages or electric fields. It is therefore advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this device.

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Fig. 1 -- MBM 10470A BLOCK DIAGRAM



TRUTH TABLE

CS	INPUT		OUTPUT	MODE
	WE	D <sub>IN</sub>		
H	X	X	L	DISABLED
L	L	H	L	WRITE "H"
L	L	L	L	WRITE "L"
L	H	X	D <sub>OUT</sub>	READ

H = High Voltage Level  
 L = Low Voltage Level  
 X = Don't care

FUNCTIONAL DESCRIPTION

The Fujitsu MBM 10470A is fully decoded 4096-bit read/write random access memory organized as 4096 words by one bit. Memory cell selection is achieved by means of a 12-bit address designated A<sub>0</sub> through A<sub>11</sub>. The active low Chip Select ( $\overline{CS}$ ) input is provided for memory expansion. The read and write operations are controlled by the state of the active low Write Enable ( $\overline{WE}$ ) input. With  $\overline{WE}$  and  $\overline{CS}$

held low, the data at D<sub>IN</sub> is written into the addressed location. To read,  $\overline{WE}$  is held high, while  $\overline{CS}$  is held low. Data at the addressed location is then transferred to D<sub>OUT</sub> and read out non-inverted. Open emitter outputs are provided to allow for maximum flexibility in output wired-OR connection.

## GUARANTEED OPERATING CONDITIONS

(Referenced to  $V_{CC}$ )

Parameter	Symbol	Min	Typ	Max	Unit	Ambient Temperature for DIP, Case Temperature for Flat Package and LCC
Supply Voltage	$V_{EE}$	-5.46	-5.2	-4.94	V	0°C to 75°C

## DC CHARACTERISTICS

( $V_{CC} = 0V$ ,  $V_{EE} = -5.2V$ , Output Load = 50Ω and 30pF to -2.0V,  $T_A = 0^\circ C$  to 75°C for DIP, Airflow  $\geq 2.5m/s$ ,  $T_C = 0^\circ C$  to 75°C for Flat Package and LCC unless otherwise noted.)

Parameter	Symbol	Min	Typ	Max	Unit	$T_A/T_C$
Output High Voltage ( $V_{IN} = V_{IH \max}$ or $V_{IL \min}$ )	$V_{OH}$	-1000 -960 -900		-840 -810 -720	mV	0°C 25°C 75°C
Output Low Voltage ( $V_{IN} = V_{IH \max}$ or $V_{IL \min}$ )	$V_{OL}$	-1870 -1850 -1830		-1665 -1650 -1625	mV	0°C 25°C 75°C
Output High Voltage ( $V_{IN} = V_{IH \min}$ or $V_{IL \max}$ )	$V_{OHC}$	-1020 -980 -920			mV	0°C 25°C 75°C
Output Low Voltage ( $V_{IN} = V_{IH \min}$ or $V_{IL \max}$ )	$V_{OLC}$			-1645 -1630 -1605	mV	0°C 25°C 75°C
Input High Voltage (Guaranteed Input Voltage High for All Inputs)	$V_{IH}$	-1145 -1105 -1045		-840 -810 -720	mV	0°C 25°C 75°C
Input Low Voltage (Guaranteed Input Voltage Low for All Inputs)	$V_{IL}$	-1870 -1850 -1830		-1490 -1475 -1450	mV	0°C 25°C 75°C
Input High Current ( $V_{IN} = V_{IH \max}$ )	$I_{IH}$			-220	μA	0°C to 75°C
Input Low Current ( $V_{IN} = V_{IL \min}$ )	$I_{IL}$	-50			μA	0°C to 75°C
CS Input Low Current ( $V_{IN} = V_{IL \min}$ )	$I_{IL}$	0.5		170	μA	0°C to 75°C
Power Supply Current (All Inputs and Output Open)	$I_{EE}$	-200			mA	0°C to 75°C

## CAPACITANCE

Parameter	Symbol	Min	Typ	Max	Unit
Input Pin Capacitance	$C_{IN}$		4		pF
Output Pin Capacitance	$C_{OUT}$		6		pF

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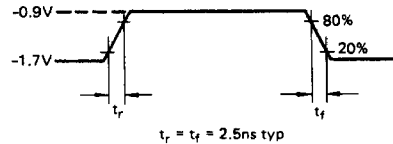
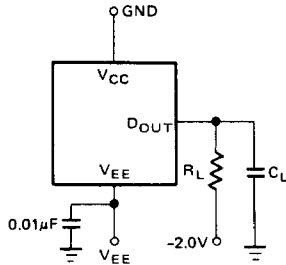


**MBM 10470A-10**  
**MBM 10470A-15**  
**MBM 10470A-20**

## AC CHARACTERISTICS

( $V_{CC} = 0V$ ,  $V_{EE} = -5.2V \pm 5\%$ , Output Load =  $50\Omega$  to  $-2.0V$  and  $30pF$  to GND,  $T_A = 0^\circ C$  to  $75^\circ C$  for DIP, Airflow  $\geq 2.5m/s$ ,  $T_C = 0^\circ C$  to  $75^\circ C$  for Flat Package and LCC, unless otherwise noted.)

Fig. 2 - AC TEST CONDITIONS



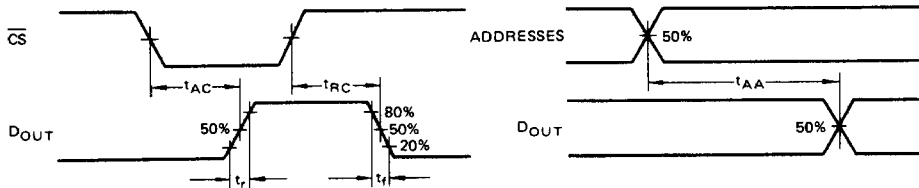
Output Load:  $R_L = 50\Omega$   
 $C_L = 30pF$   
 (including jig and stray capacitance)

NOTE: All timing measurements referenced to 50% input levels.

## READ CYCLE

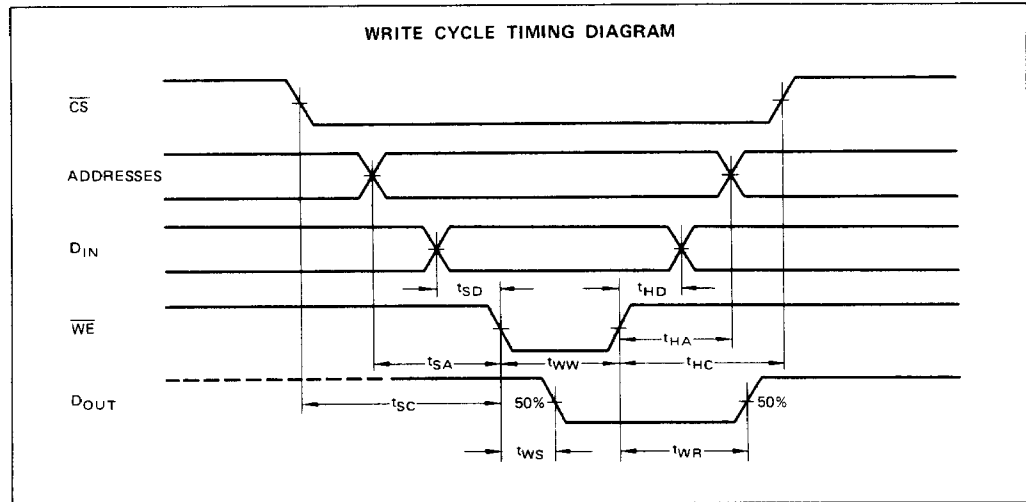
Parameter	Symbol	MBM 10470A-10			MBM 10470A-15			MBM 10470A-20			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Address Access Time	$t_{AA}$			10			15			20	ns
Chip Select Access Time	$t_{AC}$			6			8			15	ns
Chip Select Recovery Time	$t_{RC}$			6			8			15	ns

## READ CYCLE TIMING DIAGRAMS



**WRITE CYCLE**

Parameter	Symbol	MBM 10470A-10			MBM 10470A-15			MBM 10470A-20			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Write Pulse Width	$t_{WW}$	12			15			15			ns
Write Disable Time	$t_{WS}$			6			8			15	ns
Write Recovery Time	$t_{WR}$			10			10			15	ns
Address Set Up Time	$t_{SA}$	1			1			3			ns
Chip Select Set Up Time	$t_{SC}$	1			1			2			ns
Data Set Up Time	$t_{SD}$	1			1			2			ns
Address Hold Time	$t_{HA}$	2			2			2			ns
Chip Select Hold Time	$t_{HC}$	2			2			2			ns
Data Hold Time	$t_{HD}$	2			2			2			ns



**RISE TIME and FALL TIME**

Parameter	Symbol	MBM 10470A-10			MBM 10470A-15			MBM 10470A-20			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Output Rise Time	$t_r$		1.5			1.5			1.5		ns
Output Fall Time	$t_f$		1.5			1.5			1.5		ns

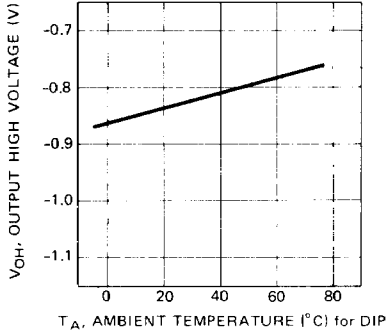
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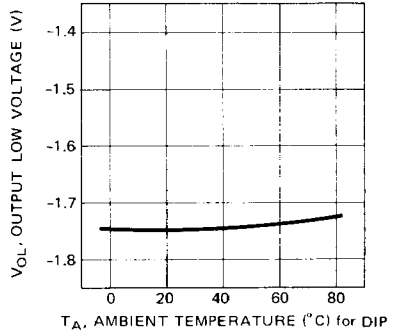
**MBM 10470A-10**  
**MBM 10470A-15**  
**MBM 10470A-20**

## TYPICAL CHARACTERISTICS CURVES

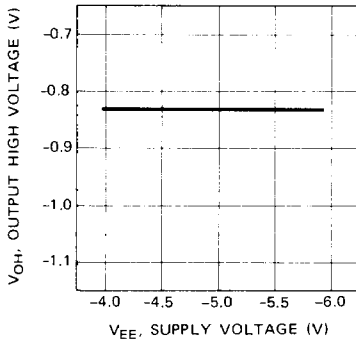
**Fig. 3 – OUTPUT HIGH VOLTAGE vs AMBIENT TEMPERATURE**



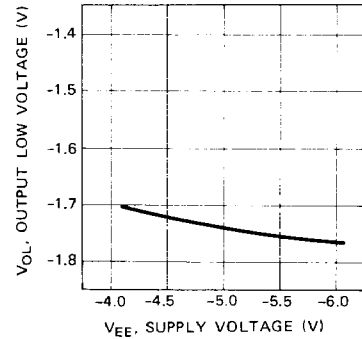
**Fig. 4 – OUTPUT LOW VOLTAGE vs AMBIENT TEMPERATURE**



**Fig. 5 – OUTPUT HIGH VOLTAGE vs SUPPLY VOLTAGE**



**Fig. 6 – OUTPUT LOW VOLTAGE vs SUPPLY VOLTAGE**



**Fig. 7 – SUPPLY CURRENT vs AMBIENT TEMPERATURE**

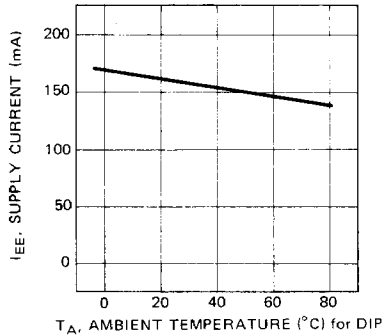


Fig. 8 - ADDRESS ACCESS TIME vs SUPPLY VOLTAGE

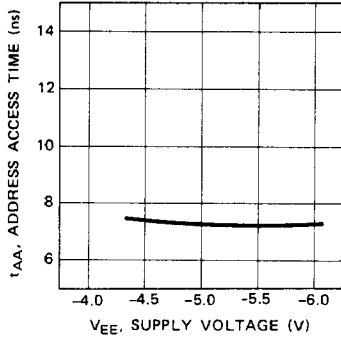


Fig. 9 - ADDRESS ACCESS TIME vs AMBIENT TEMPERATURE

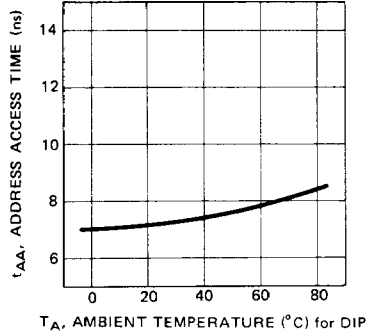


Fig. 10 - WRITE PULSE WIDTH vs SUPPLY VOLTAGE

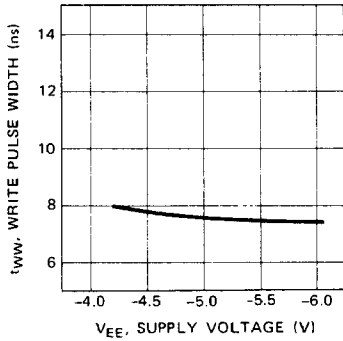
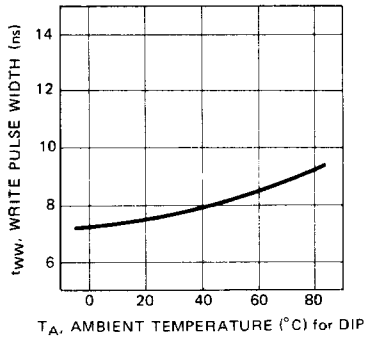


Fig. 11 - WRITE PULSE WIDTH vs AMBIENT TEMPERATURE

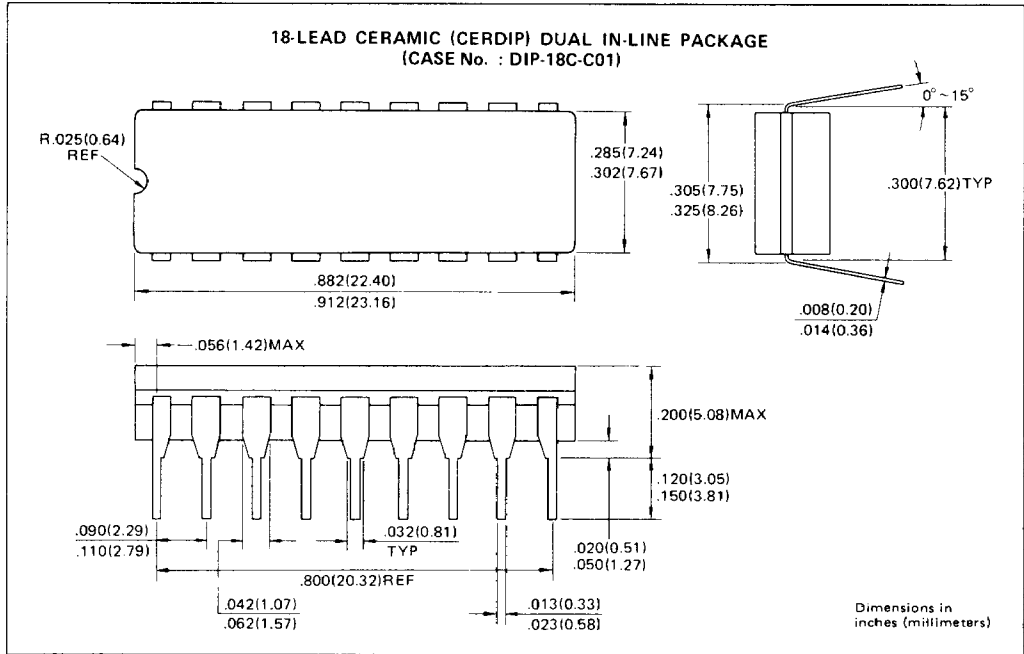




**MBM 10470A-10**  
**MBM 10470A-15**  
**MBM 10470A-20**

## PACKAGE DIMENSIONS

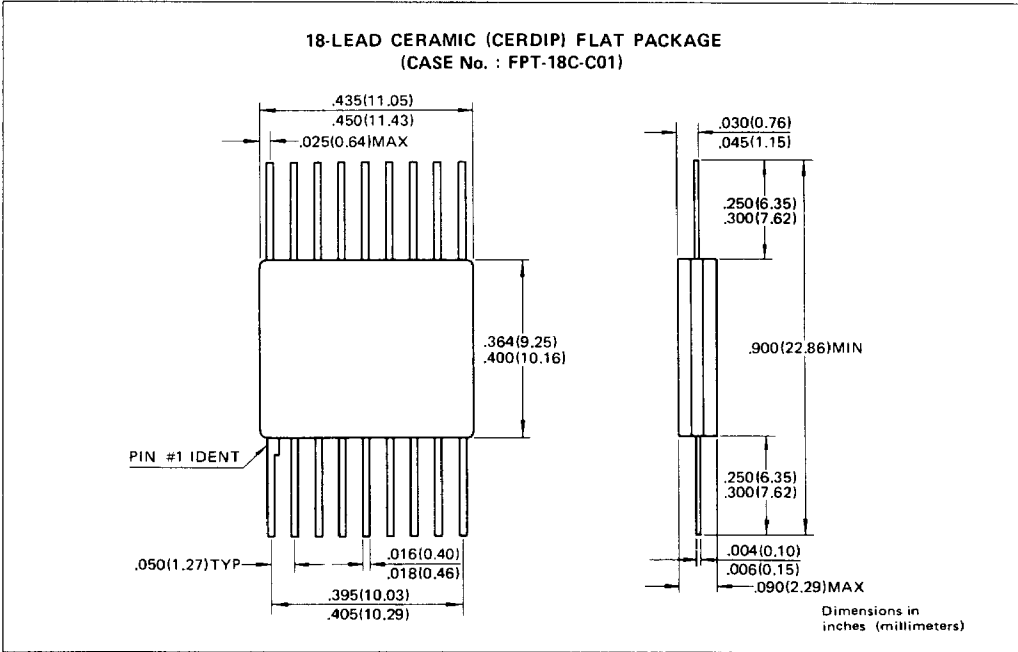
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# PACKAGE DIMENSIONS



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MBM 10470A-10  
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 MBM 10470A-20

## PACKAGE DIMENSIONS

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